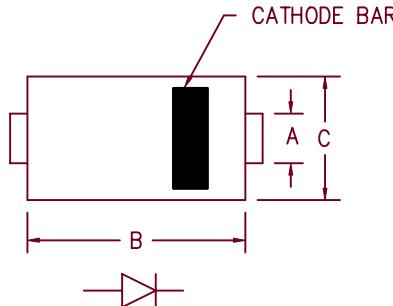
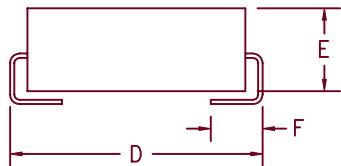


1 Amp Ultra Low Forward Voltage Schottky Diode

LSM115J



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.073	.087	1.85	2.21	
B	.160	.180	4.06	4.57	
C	.130	.155	3.30	3.94	
D	.205	.220	5.21	5.59	
E	.075	.130	1.91	3.30	
F	.030	.060	.760	1.52	



DO-214BA Package

Microsemi
Catalog Number

Working
Peak Reverse
Voltage

LSM115J

Repetitive
Peak Reverse
Voltage

15V

- Schottky Barrier Rectifier
- Guard Ring For Reverse Protection
- Low Power Loss, High Efficiency
- 100°C Junction Temperature
- V_{RRM} 15V
- High Surge Capability
- Ultra Low Forward Voltage
- Schottky OR'ing diode

Electrical Characteristics

Average forward current

$I_F(AV)$ 1 Amps

$T_L = 65^\circ\text{C}$, Square wave, $R_{\theta JL} = 15^\circ\text{C/W}$

Maximum surge current

I_{FSM} 50 Amps

8.3ms, half sine, $T_J = 100^\circ\text{C}$

Maximum peak forward voltage

V_{FM} 0.29 Volts

$|FM = 1.0A: T_J = 25^\circ\text{C}^*$

Maximum peak reverse current

$|RM$ 500 mA

$V_{RRM} = 15V, T_J = 100^\circ\text{C}$

Maximum peak reverse current

$|RM$ 200 mA

$V_R = 5V, T_J = 100^\circ\text{C}$

Maximum peak reverse current

$|RM$ 100 mA

$V_R = 3.3V, T_J = 100^\circ\text{C}$

Maximum peak reverse current

$|RM$ 10 mA

$V_{RRM} = 15V, T_J = 25^\circ\text{C}$

Typical junction capacitance

C_J 120pF

$T_J = 25^\circ\text{C}, V_R = 5V$

*Pulse test: Pulse width 300 μsec . Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range

T_{STG}

-55°C to 150°C

Operating junction temp range

T_J

-55°C to 100°C

Maximum thermal resistance

$R_{\theta JL}$

15°C/W Junction to Lead

Weight

.0047 ounces (.013 grams) typical

LSM115J

Figure 1
Typical Forward Characteristics

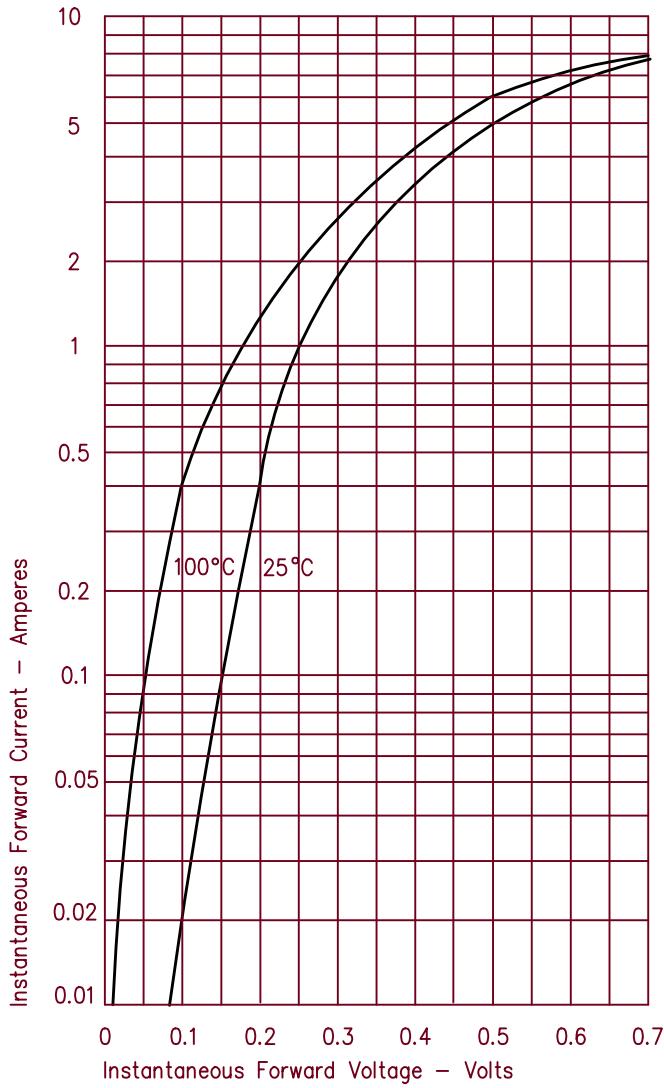


Figure 3
Typical Junction Capacitance

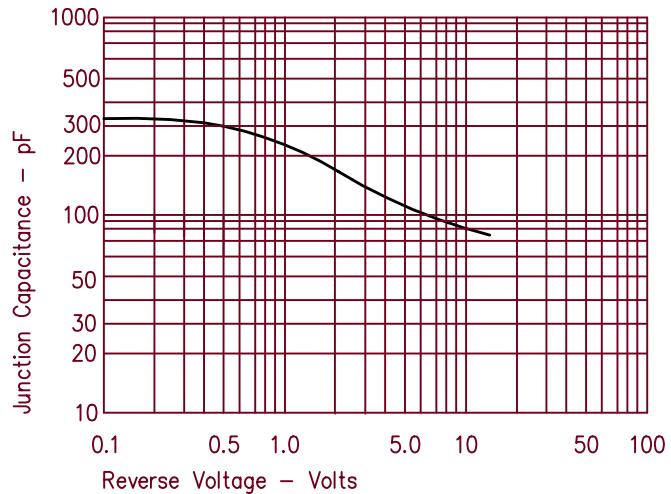
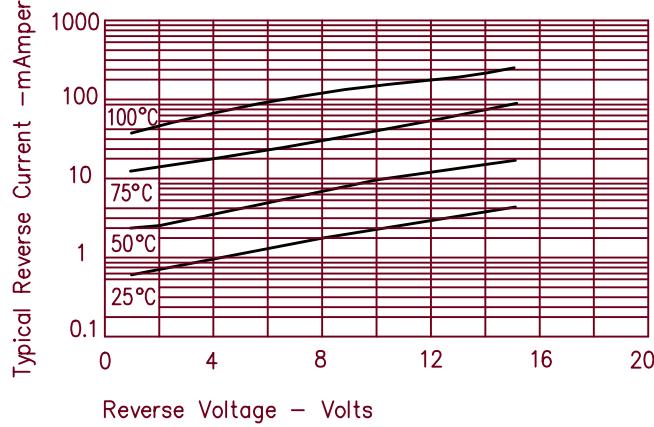


Figure 2
Typical Reverse Characteristics



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